NSN 5961-00-313-7313



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-313-7313 **Inclosure Material:** Metal and glass **Overall Length:** 1.450 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak reverse voltage and 500.0 nonrepetitive peak reverse voltage and 400.0 reverse voltage, instantaneous and 500.0 breakdown voltage, dc **Current Rating Per Characteristic:** 85.00 amperes collector current, dc and 1500.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 180.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**

No Fiig:

Demilitarization:

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